HEF4066B-Q100

Quad single-pole single-throw analog switch Rev. 1 — 7 August 2012

Product data sheet

1. **General description**

The HEF4066B-Q100 provides four single-pole, single-throw analog switch functions. Each switch has two input/output terminals (nY and nZ) and an active HIGH enable input (nE). When nE is LOW, the analog switch is turned off.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

Features and benefits 2.

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
 - ◆ Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Fully static operation
- 5 V, 10 V, and 15 V parametric ratings
- Standardized symmetrical output characteristics
- ESD protection:
 - MIL-STD-833, method 3015 exceeds 2000 V
 - ♦ HBM JESD22-A114F exceeds 2000 V
 - ightharpoonup MM JESD22-A115-A exceeds 200 V (C = 200 pF, R = 0 Ω)
- Inputs and outputs are protected against electrostatic effects
- Complies with JEDEC standard JESD 13-B

3. **Applications**

- Industrial and automotive
- Analog multiplexing and demultiplexing
- Digital multiplexing and demultiplexing
- Signal gating

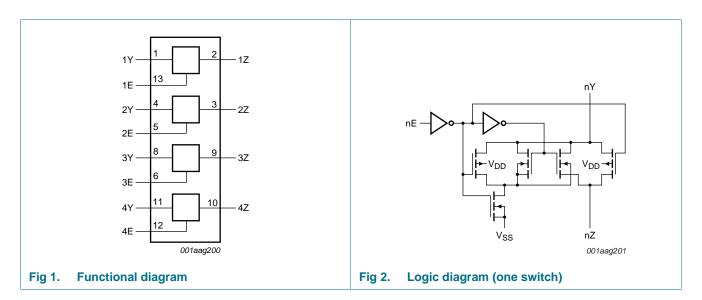
Ordering information

Table 1. **Ordering information**

Type number	Package			
	Temperature range	Name	Description	Version
HEF4066BT-Q100	–40 °C to +125 °C	SO14	plastic small outline package; 14 leads; body width 3.9 mm	SOT108-1

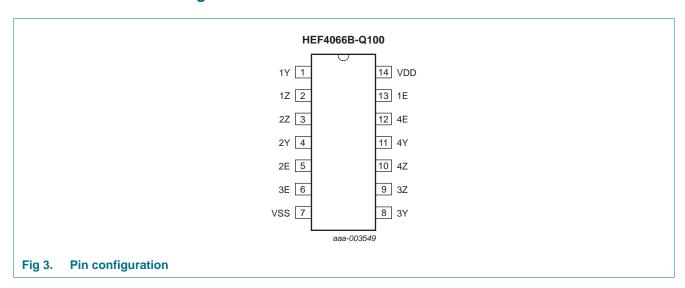


5. Functional diagram



6. Pinning information

6.1 Pinning



6.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
1Y, 2Y, 3Y, 4Y	1, 4, 8, 11	independent input or output
1Z, 2Z, 3Z, 4Z	2, 3, 9, 10	independent input or output
1E, 2E, 3E, 4E	13, 5, 6, 12	enable input (active HIGH)
V _{SS}	7	ground (0 V)
V_{DD}	14	supply voltage

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7. Functional description

Table 3. Function table[1]

Input nE	Switch
Н	ON
L	OFF

^[1] H = HIGH voltage level; L = LOW voltage level.

8. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to V_{SS} = 0 V (ground).

					-
Symbol	Parameter	Conditions	Min	Max	Unit
V_{DD}	supply voltage		-0.5	+18	V
I _{IK}	input clamping current	$V_I < -0.5 \text{ V or } V_I > V_{DD} + 0.5 \text{ V}$	-	±10	mA
VI	input voltage		-0.5	$V_{DD} + 0.5$	V
I _{I/O}	input/output current		<u>[1]</u> -	±10	mA
T _{stg}	storage temperature		-65	+150	°C
T _{amb}	ambient temperature		-40	+85	°C
P _{tot}	total power dissipation	$T_{amb} = -40 ^{\circ}\text{C} \text{ to } +85 ^{\circ}\text{C}$	[2] _	500	mW
Р	power dissipation	per switch	-	100	mW

^[1] To avoid drawing V_{DD} current out of terminal nZ, when switch current flows into terminals nY, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminal nZ, no V_{DD} current flows out of terminals nY. In this case, there is no limit for the voltage drop across the switch, but the voltages at nY and nZ may not exceed V_{DD} or V_{SS}.

9. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{DD}	supply voltage		3	-	15	V
V _I	input voltage		0	-	V_{DD}	V
T _{amb}	ambient temperature	in free air	-40	-	+125	°C
Δt/ΔV	input transition rise and fall rate	$V_{DD} = 5 V$	-	-	3.75	μs/V
		V _{DD} = 10 V	-	-	0.5	μs/V
		V _{DD} = 15 V	-	-	0.08	μs/V

^[2] For SO14 packages: above $T_{amb} = 70 \, ^{\circ}\text{C}$, P_{tot} derates linearly with 8 mW/K.

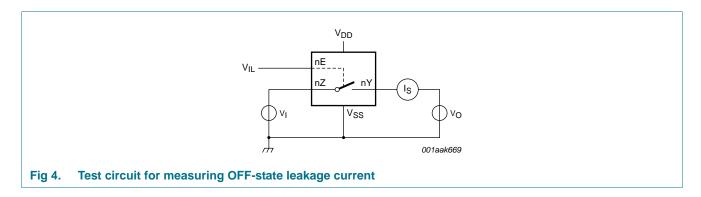
10. Static characteristics

Table 6. Static characteristics

 $V_{SS} = 0$ V; $V_I = V_{SS}$ or V_{DD} unless otherwise specified.

Symbol	Parameter	Conditions	V_{DD}	T _{amb} =	-40 °C	T _{amb} =	25 °C	T _{amb} =	= 85 °C	T _{amb} =	125 °C	Uni
				Min	Max	Min	Max	Min	Max	Min	Max	
V_{IH}	HIGH-level	$ I_{O} < 1 \mu A$	5 V	3.5	-	3.5	-	3.5	-	3.5	-	٧
	input voltage		10 V	7.0	-	7.0	-	7.0	-	7.0	-	٧
			15 V	11.0	-	11.0	-	11.0	-	11.0	-	٧
V_{IL}	LOW-level	$ I_{O} < 1 \mu A$	5 V	-	1.5	-	1.5	-	1.5	-	1.5	V
	input voltage		10 V	-	3.0	-	3.0	-	3.0	-	3.0	V
			15 V	-	4.0	-	4.0	-	4.0	-	4.0	V
I _I	input leakage current		15 V	-	±0.1	-	±0.1	-	±1.0	-	±1.0	μΑ
I _{S(OFF)}	OFF-state leakage current	per channel; see <u>Figure 4</u>	15 V	-	-	-	200	-	-	-	-	nA
I _{DD}	supply current	•	5 V	-	1.0	-	1.0	-	7.5	-	7.5	μΑ
		combinations	10 V	-	2.0	-	2.0	-	15.0	-	15.0	μΑ
			15 V	-	4.0	-	4.0	-	30.0	-	30.0	μΑ
Cı	input capacitance	nE input	-	-	-	-	7.5	-	-	-	-	pF

10.1 Test circuit



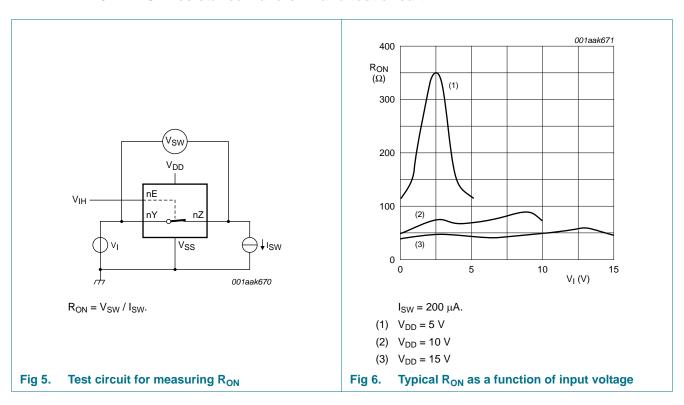
10.2 ON resistance

Table 7. ON resistance

 $T_{amb} = 25$ °C; $I_{SW} = 200 \mu A$; $V_{SS} = 0 V$.

Symbol	Parameter	Conditions	V_{DD}	Тур	Max	Unit
R _{ON(peak)}	ON resistance (peak)	$V_I = 0 \text{ V to } V_{DD}$; see Figure 5 and	5 V	350	2500	Ω
		Figure 6	10 V	80	245	Ω
			15 V	60	175	Ω
R _{ON(rail)}	ON resistance (rail)	V _I = 0 V; see <u>Figure 5</u> and <u>Figure 6</u>	5 V	115	340	Ω
			10 V	50	160	Ω
			15 V	40	115	Ω
		$V_I = V_{DD}$; see <u>Figure 5</u> and <u>Figure 6</u>	5 V	120	365	Ω
			10 V	65	200	Ω
			15 V	50	155	Ω
ΔR_{ON}	ON resistance mismatch	V _I = 0 V to V _{DD} ; see <u>Figure 5</u>	5 V	25	-	Ω
	between channels		10 V	10	-	Ω
			15 V	5	-	Ω

10.2.1 ON resistance waveform and test circuit



11. Dynamic characteristics

Table 8. Dynamic characteristics

 $T_{amb} = 25$ °C; $V_{SS} = 0$ V; for test circuit see Figure 9.

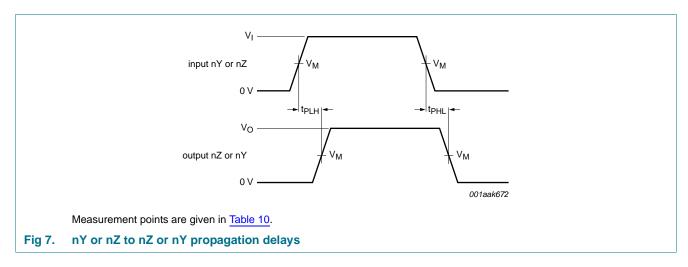
Symbol	Parameter	Conditions	V_{DD}	Тур	Max	Unit
t _{PHL}	HIGH to LOW propagation delay	nY, nZ to nZ, nY; see Figure 7	5 V	10	20	ns
			10 V	5	10	ns
			15 V	5	10	ns
		nY, nZ to nZ, nY; see Figure 7	5 V	10	20	ns
			10 V	5	10	ns
			15 V	5	10	ns
t _{PHZ} HIGH to OFF-state propagation delay		nE to nY, nZ; see Figure 8	5 V	80	160	ns
		10 V	65	130	ns	
			15 V	60	120	ns
t _{PZH}	OFF-state to HIGH	nE to nY, nZ; see Figure 8	5 V	40	80	ns
	propagation delay		10 V	20	40	ns
			15 V	15	30	ns
t _{PLZ}	LOW to OFF-state	nE to nY, nZ; see Figure 8	5 V	80	160	ns
	propagation delay		10 V	70	140	ns
			15 V	70	140	ns
t _{PZL}	OFF-state to LOW	nE to nY, nZ; see Figure 8	5 V	45	90	ns
	propagation delay		10 V	20	40	ns
			15 V	15	30	ns

Table 9. Dynamic power dissipation P_D

 P_D can be calculated from the formulas shown; $V_{SS} = 0 \text{ V}$; $t_r = t_f \le 20 \text{ ns}$; $T_{amb} = 25 \text{ }^{\circ}\text{C}$.

Symbol	Parameter	V_{DD}	Typical formula for P _D (μW)	where:		
P_D	dynamic power	5 V	$P_D = 2500 \times f_i + \Sigma (f_o \times C_L) \times V_{DD}^2$	f _i = input frequency in MHz;		
•	dissipation	10 V	$P_D = 11500 \times f_i + \Sigma (f_o \times C_L) \times V_{DD}^2$	f _o = output frequency in MHz;		
		15 V	$P_D = 29000 \times f_i + \Sigma (f_o \times C_L) \times V_{DD}^2$	C_L = output load capacitance in pF;		
				V _{DD} = supply voltage in V;		
				$\Sigma(C_L \times f_o)$ = sum of the outputs.		

11.1 Waveforms and test circuit



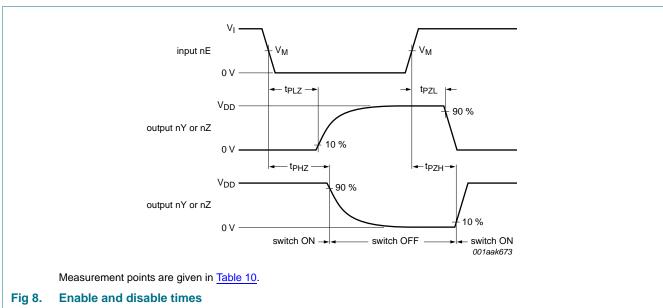
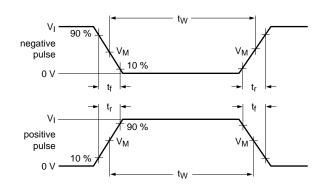
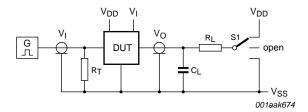


Table 10. Measurement points

Supply voltage	Input	Output
V_{DD}	V _M	V _M
5 V to 15 V	0.5V _{DD}	0.5V _{DD}





Test data is given in Table 11.

Definitions:

DUT = Device Under Test.

 R_T = Termination resistance should be equal to output impedance Z_0 of the pulse generator.

 C_L = Load capacitance including test jig and probe.

R_L = Load resistance.

Fig 9. Test circuit for measuring switching times

Table 11. Test data

Supply voltage	Input		Load		S1 position		
V_{DD}	VI	t _r , t _f	C _L	R _L	t _{PHL} , t _{PLH}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}
5 V to 15 V	0 V or V _{DD}	≤ 20 ns	50 pF	10 kΩ	V _{SS}	V _{SS}	V_{DD}

11.2 Additional dynamic parameters

Table 12. Additional dynamic characteristics

 $V_{SS} = 0$ V; $T_{amb} = 25$ °C.

Symbol	Parameter	Conditions	V_{DD}	Тур	Max	Unit
THD	total harmonic distortion	see Figure 10; $R_L = 10 \text{ k}\Omega$; $C_L = 15 \text{ pF}$;	5 V	<u>[1]</u> 0.25	-	%
		channel ON; $V_I = 0.5V_{DD}$ (p-p); $f_i = 1 \text{ kHz}$	10 V	<u>[1]</u> 0.04	-	%
		1 ₁ - 1 KHZ	15 V	[1] 0.04	-	%
V _{ct}	crosstalk voltage	nE input to switch; see Figure 11; $R_L = 10 \text{ k}\Omega$; $C_L = 15 \text{ pF}$; $nE = V_{DD}$ (square-wave)	10 V	50	-	mV

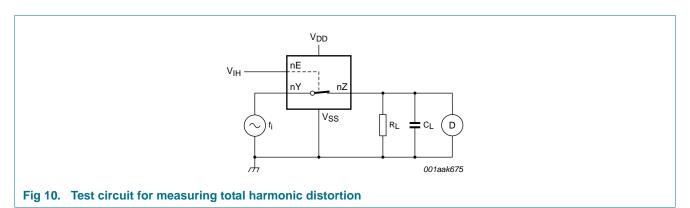
 Table 12. Additional dynamic characteristics ...continued

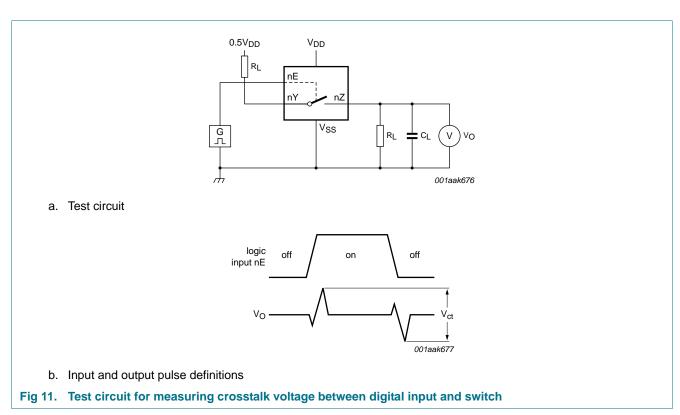
 $V_{SS} = 0$ V; $T_{amb} = 25$ °C.

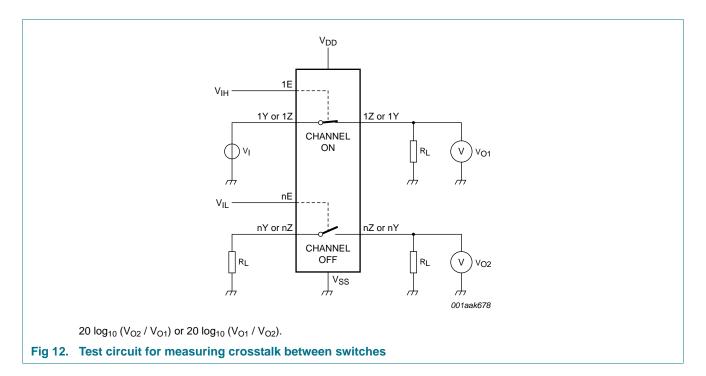
Symbol	Parameter	Conditions	V_{DD}	Тур	Max	Unit
Xtalk	crosstalk	between switches; see Figure 12; f_i = 1 MHz; R_L = 1 k Ω ; V_I = 0.5 V_{DD} (p-p)	10 V	<u>[1]</u> –50	-	dB
α_{iso}	isolation (OFF-state)	see Figure 13; f_i = 1 MHz; R_L = 1 k Ω ; C_L = 5 pF; V_I = 0.5 V_{DD} (p-p)	10 V	<u>[1]</u> –50	-	dB
f _(-3dB)	-3 dB frequency response	see Figure 14; $R_L = 1 \text{ k}\Omega$; $C_L = 5 \text{ pF}$; $V_I = 0.5V_{DD}$ (p-p)	10 V	[1] 90	-	MHz

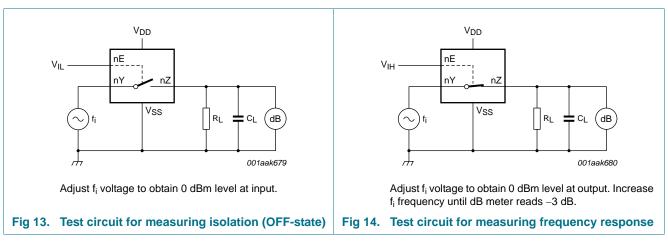
[1] f_i is biased at 0.5 V_{DD} .

11.2.1 Test circuits





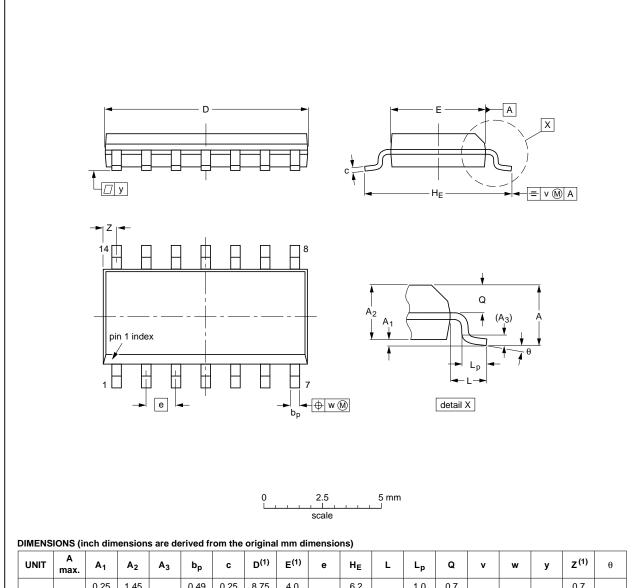




12. Package outline

SO14: plastic small outline package; 14 leads; body width 3.9 mm

SOT108-1



UNIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	у	z ⁽¹⁾	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	8.75 8.55	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8°
inches	0.069	0.010 0.004	0.057 0.049	0.01		0.0100 0.0075	0.35 0.34	0.16 0.15	0.05	0.244 0.228	0.041	0.039 0.016	0.028 0.024	0.01	0.01	0.004	0.028 0.012	0°

Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	JEITA	PROJECTION		
SOT108-1	076E06	MS-012			99-12-27 03-02-19	

Fig 15. Package outline SOT108-1 (SO14)

HEF4066B_Q100

13. Abbreviations

Table 13. Abbreviations

Acronym	Description
HBM	Human Body Model
ESD	ElectroStatic Discharge
MM	Machine Model
MIL	Military

14. Revision history

Table 14. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
HEF4066B_Q100 v.1	20120807	Product specification	-	-

15. Legal information

15.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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HEF4066B-Q100

Quad single-pole single-throw analog switch

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